# RESULTS

### To Our Shareholders:

Varian Semiconductor, like other semiconductor capital equipment suppliers, is experiencing the most difficult period in our industry's history. The demand for semiconductor capital equipment weakened sharply and suddenly at the end of fiscal 2000. During fiscal 2001, economic and political forces combined to further weaken demand and reverse the momentum that had been driving our business.

Fundamentally, however, our business has not changed. Cyclical peaks and troughs are normal in our industry, and we have successfully dealt with both extremes in the past – emerging from each down cycle stronger on the upside. Although the current downturn is particularly difficult, we are employing aggressive tactics to manage successfully through it with strong traction for the anticipated upturn.

One of the keys to our success is that we develop and sell technology that enables our customers to produce their next generation products and also improve the cost and performance of their existing products. Our new 300mm VIISta platform of single wafer tools will help lead Varian Semiconductor and our customers into the next upturn.

Among our important accomplishments in the past year were:

- We successfully introduced the VIISta 3000 high energy ion implanter, completing the industryleading VIISta single wafer platform for 300mm and 200mm applications.
- We achieved 42 percent overall market share on a unit basis in ion implant, as reported by Dataquest.
- We received a patent for an advanced ion implant architecture that enables the VIISta 810



medium current implanter to improve the yield of semiconductor devices by delivering an ion beam of exceptional species and beam purity.

- We introduced our patented Post-Gate Ion Implantation (PoGI) process which has the potential of significantly reducing chipmanufacturing costs by eliminating up to four of the mask levels required during device production.
- We won first place for the fifth consecutive year as the best semiconductor capital equipment supplier, as determined by VLSI Research.
   VLSI Research's survey led them to designate
   VSEA as a "technology and customer satisfaction powerhouse."



## A Differentiated Strategy

We continue to invest substantially in R&D, developing advanced technologies to manufacture next generation devices. The VIISta single wafer common platform is clearly differentiated from competitive products. VIISta leads an industrywide transition to single wafer processing in ion implantation.

At industry meetings, we have seen a growing awareness of our platform's advantages. Recent orders for our 300mm tools with high-tilt capabilities, the PoGI application and other features are leading indicators of our opportunity for market share gains in the next upturn.

The VIISta platform provides considerable customer advantages derived from our unique architectural approach. In short:

- Single wafer processing for all ion implant energies and doses allows customers superior processing and implant precision.
- VIISta single wafer implanters have the highest throughputs in the industry.

The common control system and wafer handling capabilities of the VIISta platform enable fab scheduling flexibility, thus effectively reducing capital and operating costs. The VIISta 10 P²LAD, the result of over a decade of research and development, is an ultra-low energy ion implanter that uses pulsed-plasma doping in place of a traditional ion beam. The system's proprietary approach to plasma doping overcomes the technical challenges posed by the requirements of low energy doping for ultra-shallow junctions.

## Managing the Industry Cycle

During this downturn, we have refined our business model to deal with the cycle's effects. Our aim is to ensure business growth and more profitable operations when markets improve.

We are focused on two areas that will improve our operating leverage:

 Reducing our costs. We have cut ongoing operating costs in the design, production and servicing of our tools. These efforts are expected to benefit future earnings performance.  Shortening cycle times. We have reduced procurement, assembly and test times, and accelerated the introduction of engineering improvements by leveraging the benefits of the VIISta common platform.

## The Management Team

Dick Aurelio, chief executive officer, assumed the additional post of chairman on the retirement of Tracy O'Rourke, and Ernie Godshalk was promoted to the new position of president and chief operating officer and elected to the Board of Directors. We added Bob Halliday to our team as vice president and chief financial officer and Al Sheng as vice president of engineering.

We are pleased to welcome Liz Tallett to our Board of Directors. Liz is the president and chief executive officer of Dioscor, Inc. We are benefiting from her considerable experience in technology and new business development.

#### Outlook

As we look forward to the year ahead, we are in a strong position to take full advantage of the demand for new technologies. We expect to come out of this downturn with financial strength, operating leverage and leading market share.

We want to close with our sincere thanks to our shareholders, employees, customers and suppliers. We value your continuing support.

Richard A. Aurelio
Chairman and Chief Executive Officer

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Ernest L. Godshalk, III
President and Chief Operating Officer

December 17, 2001

# FINANCIAL HIGHLIGHTS

(dollars in millions)	Fiscal Year 2001 <sup>(1)</sup> (with SAB 101)	Fiscal Year 2001 <sup>(1)</sup> (pre-SAB 101)	Fiscal Year 2000 <sup>(2),(4)</sup>	Fiscal Year 1999 <sup>(3),(4)</sup>
Revenue Gross Profit Percent of Revenue Research and Development Percent of Revenue Marketing, Selling and Administrative Percent of Revenue Restructuring Costs	\$ 632.0 233.2 36.9% 49.8 7.9% 93.2 14.7% 1.9	\$ 599.5 217.2 36.2% 49.8 8.3% 93.2 15.5% 1.9	\$ 687.7 270.7 39.4% 47.0 6.8% 98.1 14.3%	\$ 271.9 92.2 33.9% 37.6 13.8% 70.3 25.9% 2.7
Operating Income (Loss) Other Income Interest Income, Net	\$ 88.3	\$ 72.3	\$ 125.6	\$ (18.4)
	-	-	18.7	2.0
	8.2	8.2	4.6	1.8
Income (Loss) before Taxes	\$ 96.5	\$ 80.5	\$ 148.9	\$ (14.6)
Tax Provision (Benefit)	31.9	26.6	49.1	(3.2)
Income (Loss) before Cumulative Effect of SAB 101 Cumulative Effect of SAB 101 Net Income (Loss)	\$ 64.6 (27.0) 37.6	\$ 53.9 - 53.9	\$ 99.8 - 99.8	\$ (11.4) - (11.4)
Net Income (Loss) Per Share - Basic	\$ 1.16	\$ 1.67	\$ 3.18	\$ (0.37)
Net Income (Loss) Per Share - Diluted	1.10	1.59	2.97	(0.37)
Backlog	\$ 160.0	\$ 109.0	\$ 360.0	\$ 181.0
Working Capital	344.8	361.1	294.1	153.7
Current Ratio	2.9	3.7	2.7	2.2
Long Term Debt	-	-	-	-
Stockholders' Equity	399.4	415.8	349.4	206.4
Total Assets	588.1	557.2	533.7	347.3

- (1) The Company adopted SAB 101 during the fourth quarter of fiscal year 2001, effective at the start of fiscal year 2001.
- (2) In fiscal year 2000, the Company recorded in Other Income a pre-tax gain of \$18.7 million (\$12.6 million after tax or \$0.37 per share) related to litigation settlements.
- (3) Prior to April 2, 1999 Varian Semiconductor Equipment Associates, Inc. was operated as the semiconductor equipment business of Varian Associates, Inc.
- (4) During the first quarter of fiscal year 2001, Varian Semiconductor changed its method of valuing domestic inventories from the last-in, first-out ("LIFO") method to the first-in, first-out ("FIFO") method. Varian Semiconductor has restated its financial statements to reflect the change to FIFO.

#### Safe Harbor Statement

This Annual Letter to Stockholders contains forward-looking statements for purposes of the safe harbor provisions of The Private Securities
Litigation Reform Act of 1995. For this purpose, the statements concerning the Company's operating outlook, sales growth, market share, capacity utilization, technology leadership, and technological capabilities and benefits are forward-looking statements and any statements using the terms "believes," "anticipates," "expects," "plans,"

or similar expressions are forward-looking statements. The forward-looking statements involve a number of risks and uncertainties. Among the important factors that could cause actual events to differ materially from those suggested or indicated by such forward-looking statements are volatility in the semiconductor equipment industry; economic conditions in general and as they affect the Company's customers; significant fluctuations in the Company's quarterly operating results; the impact of rapid technological change; the Company's dependence on the

development and introduction of new products; the Company's concentration on ion implantation systems and related products; concentration in the Company's customer base and lengthy sales cycles; the highly competitive market in which the Company competes; risks of international sales; foreign currency risks; and general economic conditions; and other factors identified in the Company's Annual Report on Form 10-K, and the most recent Quarterly Reports on Form 10-Q filed with the Securities and Exchange Commission.

# CORPORATE INFORMATION

#### Offices

Headquarters

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North America

Austin, Texas Gloucester, Massachusetts Mesa, Arizona Newark, California Newburyport, Massachusetts Palo Alto, California Plano, Texas Portland, Oregon

Europe

East Kilbride, Scotland Houten, The Netherlands Munich, Gemany Paris, France Stuttgart, Germany

Asia

Hsinchu, Taiwan Shanghai, China Singapore Songtan, Korea Yokohama, Japan

For a complete office listing, please visit our website at: www.vsea.com/company/locations

#### Management

Richard A. Aurelio Chairman & Chief Executive Officer

Ernest L. Godshalk, III
President & Chief Operating Officer

Robert J. Halliday Vice President & Chief Financial Officer

Seth H. Bagshaw Vice President & Corporate Controller

Yong-Kil Kim, Ph.D. Vice President & General Manager Asia Operations

Ralph E. Knupp, Ph.D. Vice President, Human Resources & Communications

Gary L. Loser Vice President, General Counsel & Secretary

Alan L. McKinnon, Jr. Corporate Treasurer

Brian T. Robertson Vice President, Supply Chain

Alan P. Sheng, Ph.D. Vice President, Engineering

Walter F. Sullivan

Vice President, Customer Operations & Chief Information Officer

Seiji Yoshii, Ph.D. President, Varian Semiconductor Equipment K.K., Japan

#### **Directors**

Richard A. Aurelio Chairman of the Board & Chief Executive Officer

Ernest L. Godshalk, III President & Chief Operating Officer

George W. Chamillard Chairman, President & Chief Executive Officer, Teradyne, Inc.

Robert W. Dutton, Ph.D. Director of Research, Center for Integrated Systems & Professor of Electrical Engineering, Stanford University

Angus A. MacNaughton President, Genstar Investment Corporation

Elizabeth E. Tallett President & Chief Executive Officer, Dioscor, Inc.

# STOCKHOLDER INFORMATION

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Hale and Dorr LLP
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Phone: (617) 526-6000

Independent Accountants
PricewaterhouseCoopers LLP
One Post Office Square
Boston, MA 02109-2106
Phone: (617) 478-5000

Number of Registered Stockholders 3,738 registered holders as of September 28, 2001 Stock Listing

Varian Semiconductor Equipment Associates, Inc. is traded on The Nasdaq National Market, Nasdaq Symbol: VSEA

Transfer Agent EquiServe Trust Company, N.A. PO Box 2500

Jersey City, NJ 07303 Phone: (800) 756-8200

Form 10-K

A copy of Varian Semiconductor Equipment Associates, Inc. Annual Report on Form 10-K, filed with the Securities and Exchange Commission, contains additional information relating to the Company and is available without charge at the contact below or at www.vsea.com. We welcome questions from potential and existing stockholders.

Please Contact: Investor Relations Varian Semiconductor Equipment Associates, Inc. 35 Dory Road Gloucester, MA 01930-2297 Phone: (978) 282-2303 www.vsea.com